# 2N6674 & 2N6675



## **NPN High Power Silicon Transistor**

Rev. V1

#### **Features**

- Available in JAN, JANTX, JANTXV per MIL-PRF-19500/537
- TO-3 (TO-204AA) Package



#### **Electrical Characteristics**

Parameter	Test Conditions	Symbol	Units	Min.	Max.
Off Characteristics					
Collector - Emitter Breakdown Voltage	I <sub>C</sub> = 200 mAdc 2N6674 2N6675	V <sub>(BR)CEO</sub>	Vdc	300 400	_
Collector - Emitter Cutoff Current	$V_{CE}$ = 450 Vdc, $V_{BE}$ = -1.5 Vdc, 2N6674 $V_{CE}$ = 650 Vdc, $V_{BE}$ = -1.5 Vdc, 2N6675	I <sub>CEX</sub>	Adc	_	0.1
Emitter - Base Cutoff Current	V <sub>EB</sub> = 7 Vdc	I <sub>EBO</sub>	mAdc	_	2.0
Collector - Base Cutoff Current	V <sub>CB</sub> = 450 Vdc, 2N6674	I <sub>CBO</sub>	mAdc	_	1.0
On Characteristics <sup>1</sup>					
Forward Current Transfer Ratio	$I_C$ = 1 Adc, $V_{CE}$ = 3 Vdc $I_C$ = 10 Adc, $V_{CE}$ = 2 Vdc	H <sub>FE</sub>	-	15 8	40 20
Collector - Emitter Sustaining Voltage	I <sub>C</sub> = 10 Adc, I <sub>B</sub> = 2 Adc I <sub>C</sub> = 15 Adc, I <sub>B</sub> = 5 Adc	V <sub>CE(SAT)</sub>	Vdc	_	1.0 5.0
Base - Emitter Saturation Voltage	I <sub>C</sub> = 1 Adc, I <sub>B</sub> = 2 Adc	V <sub>BE(SAT)</sub>	Vdc	_	1.5
Dynamic Characteristics					
Small-Signal Short-Circuit Forward Current Transfer Ratio	I <sub>C</sub> = 0.5 Adc, V <sub>CE</sub> = 10 Vdc, f = 1 kHz	H <sub>FE</sub>	-	3	10
Output Capacitance	$V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \le f \le 1 \text{ MHz}$	Сово	pF	150	500

<sup>1.</sup> Pulse Test: Pulse Width = 300 µs, Duty Cycle ≤2.0%.



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#### **Electrical Characteristics**

Parameter	Test Conditions	Symbol	Units	Min.	Max.
Switching Characteristics					
Delay Time Rise Time Storage Time Fall Time Cross-Over Time	See figure 3 of MIL-PRF-19500/537	T <sub>D</sub> T <sub>R</sub> T <sub>S</sub> T <sub>F</sub> T <sub>C</sub>	μs	_	0.1 0.6 2.5 0.5 0.5

#### Safe Operating Area

DC Tests:  $T_C$  = +25°C, I Cycle, t = 1.0 s (see figure 4 of MIL-PRF-19500/537)

Test 1:  $V_{CE}$  = 11.7 Vdc,  $I_C$  = 15 Adc Test 2:  $V_{CE}$  = 30 Vdc,  $I_{C}$  = 5.9 Adc  $V_{CE}$  = 100 Vdc,  $I_{C}$  = 0.25 Adc Test 3: Test 4:  $V_{CE}$  = 25 Vdc,  $I_{C}$  = 7 Adc

Test 5:  $V_{CE} = 300 \text{ Vdc}, I_{C} = 20 \text{ mAdc}, (\text{for } 2\text{N}6674)$  $V_{CE} = 400 \text{ Vdc}, I_{C} = 10 \text{ mAdc}, (\text{for 2N6675})$ 

Clamped Switch:

 $T_A = +25$ °C,  $V_{CC} = 15$  Vdc, load condition B,  $R_{BB1} = 5$   $\Omega$ ,  $R_{BB2} = 1.5$   $\Omega$ ,

 $R_{BB2}$  = 5 Vdc, L = 50  $\mu$ H, R of inductor = 0.05  $\Omega$ , RL = R of inductor, (see figure 6 of MIL-PRF-19500/537)

Clamp Voltage = 350;  $I_C$  = 10 Adc, (2N6674) Clamp Voltage = 450;  $I_C = 10 \text{ Adc}$ , (2N6675)

## **Absolute Maximum Ratings**

Ratings	Symbol	2N6674	2N6675	Units
Collector - Emitter Voltage	V <sub>CEO</sub>	300	400	Vdc
Collector - Base Voltage	V <sub>CBO/</sub> V <sub>CBX</sub>	450	650	Vdc
Emitter - Base Voltage	V <sub>EBO</sub>	-	Vdc	
Collector Current	Ic	1	Adc	
Base Current	I <sub>B</sub>	5		Adc
Total Power Dissipation  @ $T_A = +25^{\circ}C^2$ @ $T_A = +25^{\circ}C$	P <sub>T</sub>	6 <sup>3</sup> 175	3 <sup>4</sup> 175	W
Operating & Storage Temperature Range	T <sub>OP</sub> , T <sub>STG</sub>	-65 to +200		ů

<sup>2.</sup> Derate linearly @ 1.0 mW /  $^{\circ}$ C for T<sub>A</sub> >25 $^{\circ}$ C.

#### **Thermal Characteristics**

Characteristics	Symbol	Max. Value
Thermal Resistance, Junction to Case	R <sub>eJC</sub>	1°C/W

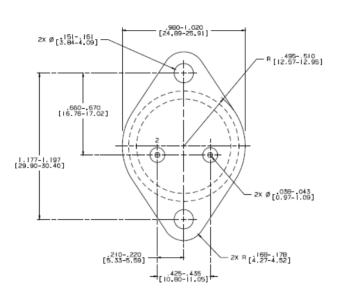
<sup>3.</sup> Derate linearly @ 34.2 mW / °C for  $T_A$  >25°C. 4. Derate linearly @ 17.1 mW / °C for  $T_A$  >25°C.

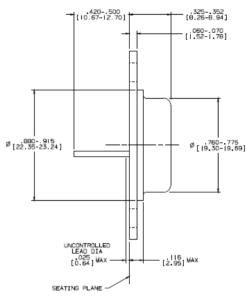


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## **Outline Drawing**





#### NOTES:

- I. STANDARD HEADER TYPE SOLID BASE. 2. STANDARD LEAD FINISHIPER WIL-W-38510 TYPE X OR EQUIVALENT. 3. LEAD NOT BENT GREATER THAN 15° 4. DIMENSIONS BASED ON JEDEC STANDARD TO-3 PUBLICATION 95, PA

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